

Compact, low-cost higher order mode absorbers formed by cold spray of metal matrix composites

DOE-NP SBIR/STTR Exchange Meeting

August 14, 2024

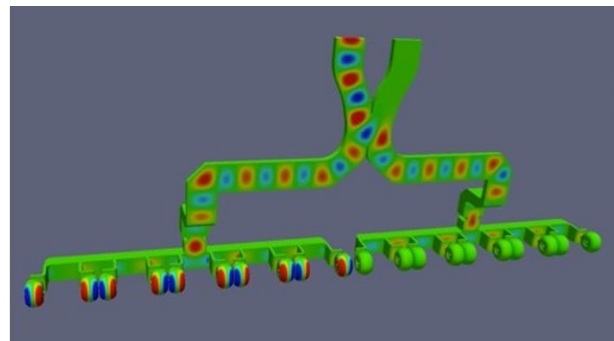
carriere@radiabeam.com

SBIR/STTR Award DE-SC0020562

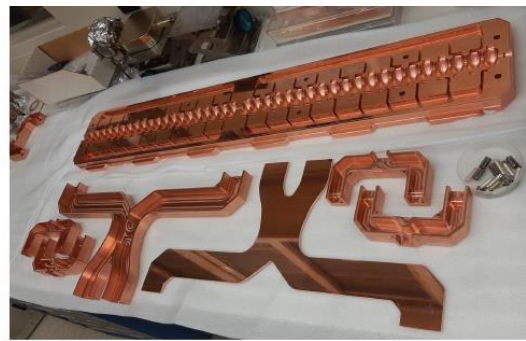
- Spin-out of UCLA Physics Department: 2004
 - Located in Santa Monica, California
 - Currently: 54 employees, 30,000 ft²
- Charge particle optics, custom magnets & >MeV X-ray systems
 - Sim, design, fab and testing of high power RF structures
 - Custom instrumentation with vac-compatible manufacturing
 - Cryogenic engineering
 - 9MeV Radiography/CT services
 - Teams: R&D, Engineering, Manufacturing, Integration & Testing
 - In-house ‘clean’ machining, aqueous cleaning & RGA outgassing



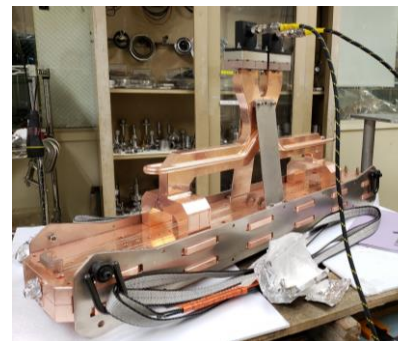
Inverse Compton scattering gamma-ray source



CST RF model



Machined components

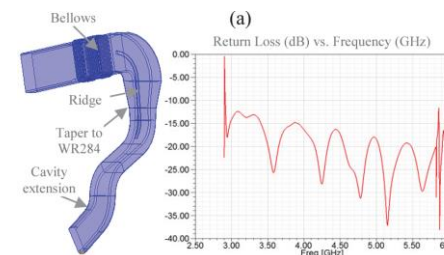


Low power RF



White room manufacturing of copper

- Motivation:** Long range wakefields at high currents can strongly affect the beam dynamics via higher order modes(HOM). As machines move to higher currents, higher bunch charges and shorter bunches, problem becomes more pronounced.
- Solution:** HOM dampeners which preserve fundamental
 - Waveguide, loop/antenna-couplers, **beam line absorber (BLA)**



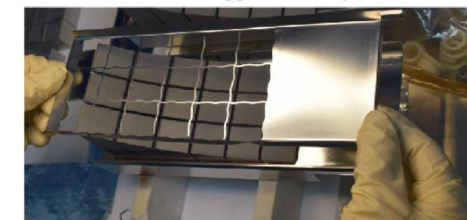
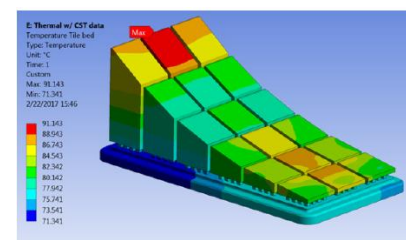
Argonne - APS WR284 Waveguide loads for SPX CM
Technology: Soldering + EBW (St Gobain Hexoloy)



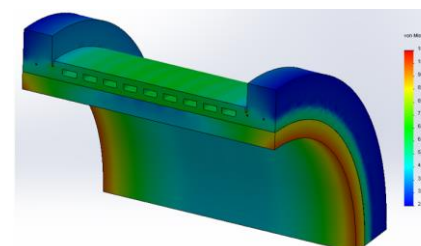
18kW high power tests of SiC
at KEK in collaboration with
Toshiba Energy Systems
Technology: SiC



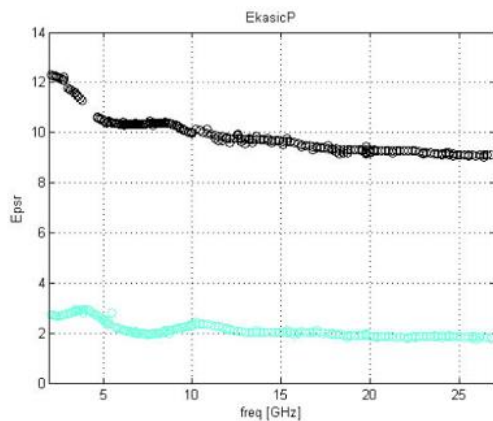
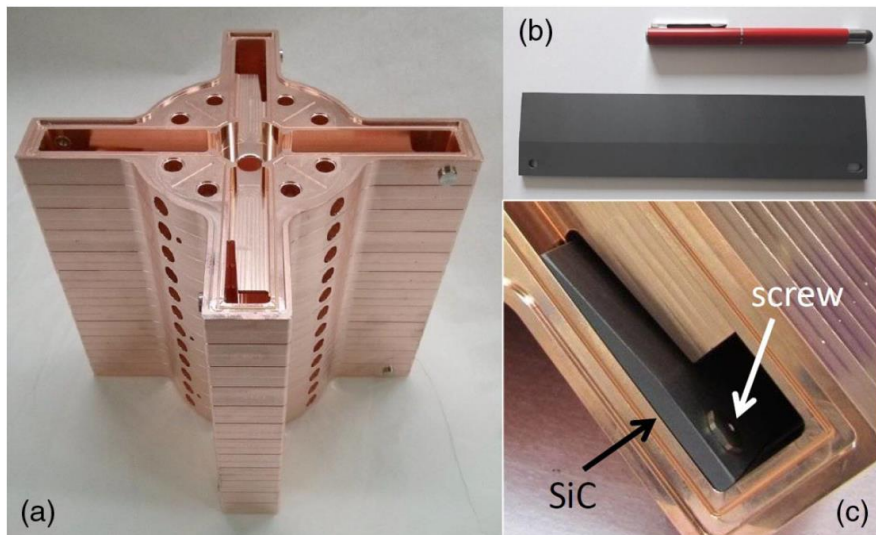
BLA developed by DESY/Kubrina Lumina (Poland)
Kubrina Lumina supplied x35 BLA assemblies to LCLS-II
Technology: Brazed 80K AlN (Sienna STL-150D)



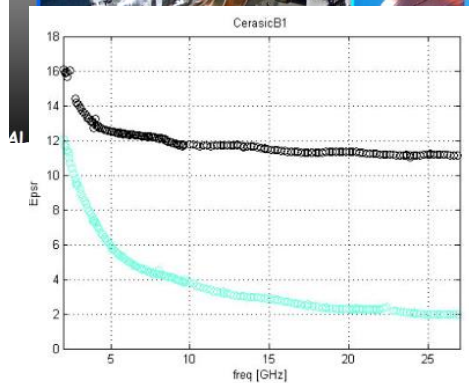
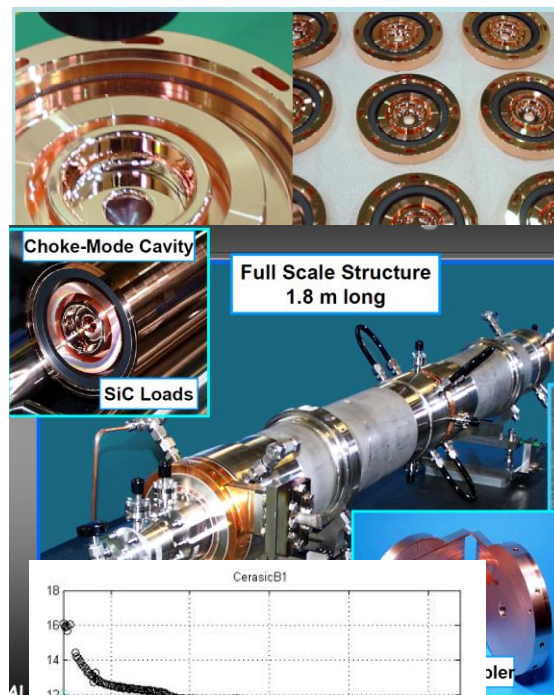
JLab prototype waveguide-load developed for Helmholtz-Zentrum Berlin
Technology: Brazed (Sienna STL-100HTZ)



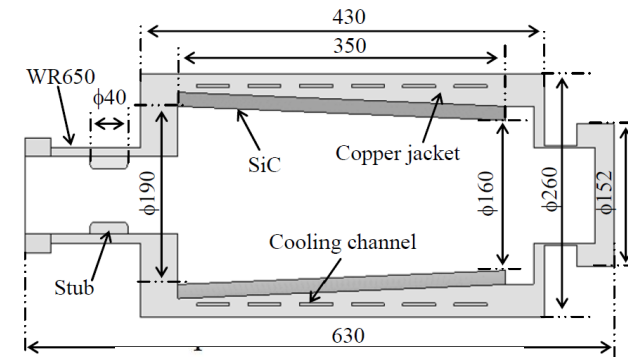
BNL LDRD three high power 308mm ID BLAs
Technology: Shrink fit SiC (Coorstek SC-35)



On-Cell waveguide loads for C-band NCRF structure
INFN & Andalo Gianni
Technology: Fastened SiC (Ekasic-P)



Choke-mode C-band NCRF structure for Spring-8
10,000+ cells
KEK & Mitsubishi Heavy Industries
Technology: SiC (CERASIC) + Spring clips



10kW, 1.428GHz
Toshiba + KEK
CERASIC from
Covalent Materials Corporation

Beam line absorber assembly requirements:

1. Amenable to bonding to a water-cooling circuit	Conventional-specification
2. Good thermal conductivity	
3. Toughness/no cracking: integrity during fabrication and under load	
4. Broadband RF absorption characteristics	
5. Minimize beam-induced electrostatic charging/finite DC surface conductivity	Accelerator-specifications
6. UHV compatible/low outgassing	
7. No dust/particulate generation	
8. Stable against high energy radiation	

Additional considerations

- Niche application with limited demand: supply and quality issues
- Ceramic variability: small RF coupons can be different than large, full-scale parts
- Establishing specifications and qualification methods requires lab support
- High power testing to failure is valuable for risk mitigation but expensive

- HOM damping is crucial for high beam current operation of EIC eSR SRF systems
 - x34 BLA assemblies: Large and small diameter
 - Self heating: 15kW/26.5kW total – reduce ϵ
- Power handling capability assembly's thermal transport circuit
 - CESR-B: limit roughly $0.2\text{W}/\text{mm}^2$
- Virtual leak due to shrink fit: $2.2\text{E}-10$ Torr-Liters/sec-cm²,
- High power tests carried out in the air
 - 704 MHz 1 MW CW klystron is delivered to the BLA with WR 1500 waveguides: Asymmetric TE₀₁ heating in SiC
 - SC-35 SiC: Radius 154mm, WT: 14mm
 - No damage at $0.44\text{ W}/\text{mm}^2$, cracks at $0.65\text{ W}/\text{mm}^2$
- Only 30% margin for SBLA #2
 - *All HOM absorbers for EIC SRF cavities will go through high power test, prior to the installation to the EIC SRF cryomodules.*

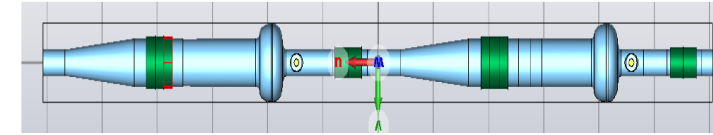


Figure 3. EIC ESR SRF cavities layout.

Table 2. HOM power absorbing in BLAs (compare lengths of SBLA)

	LBLA	SBLA #1	SBLA #2
Radius (mm)	137	75	75
Length (mm)	240	120	240
HOM power (kW)	34.4	26.5	38.3
Power flux (W/mm ²)	0.19	0.47	0.34

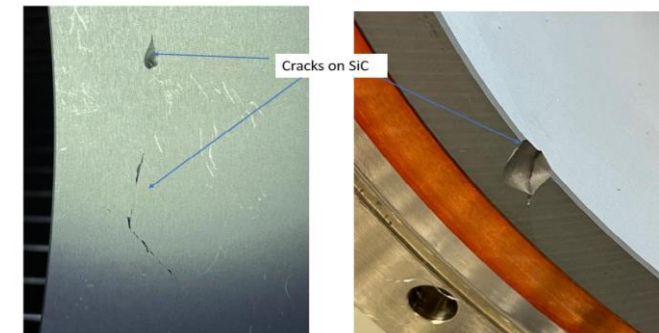
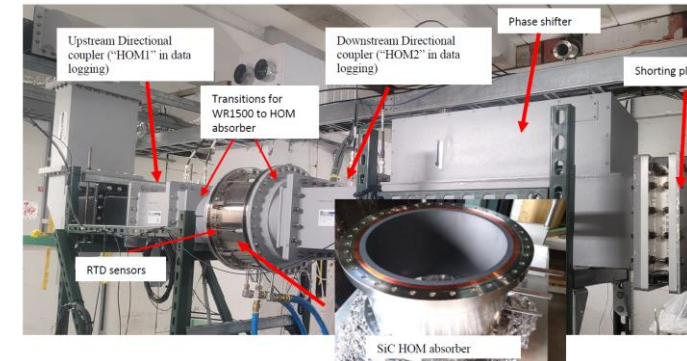
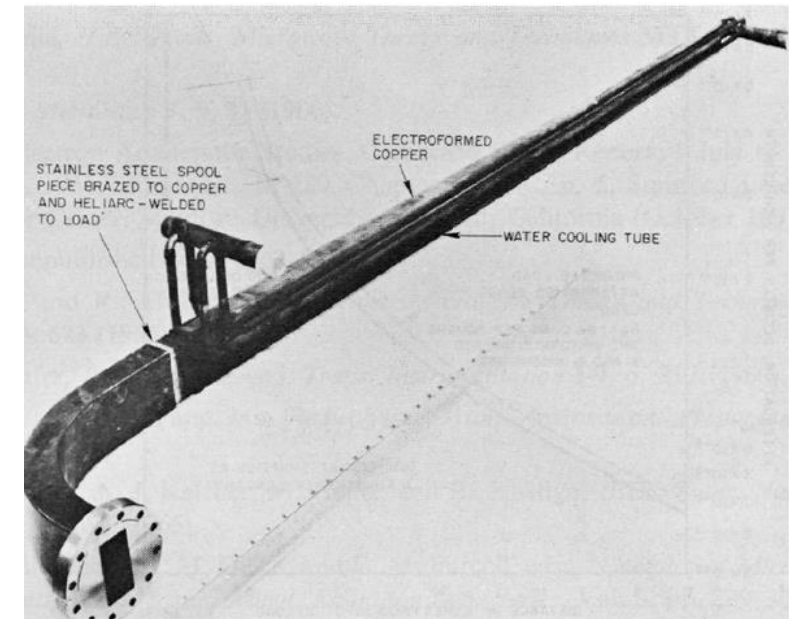
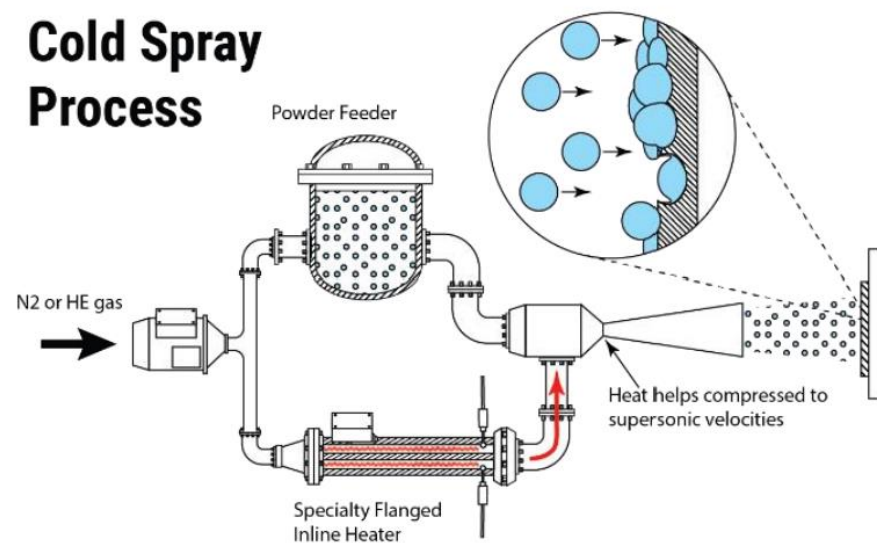


Figure 12. Crack found inside the SiC (left) and on the edge (right).

Xu, Wencan, et al. "High-power test results for a cylindrical-shell silicon carbide higher-order-mode damper." *Physical Review Accelerators and Beams* 27.3 (2024): 031601.

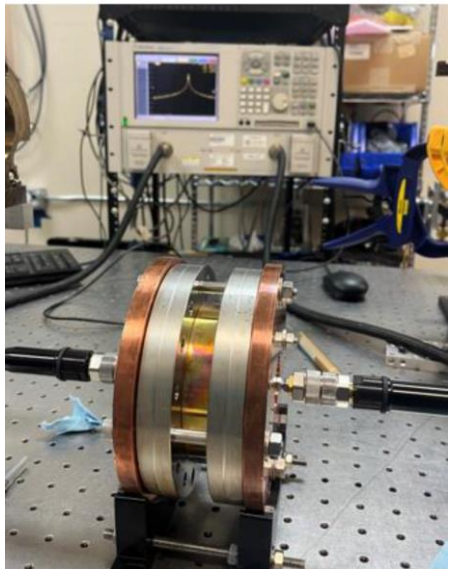
- Cold Spray: corrosion or wear resistance for repair and mitigation, dimensional restoration of mating surfaces like flanges
- Development challenges:
 - Nozzle clogging
 - High ceramic loading: feedstock \neq coating composition
 - Low porosity w/o expensive He usage

Cold Spray Process



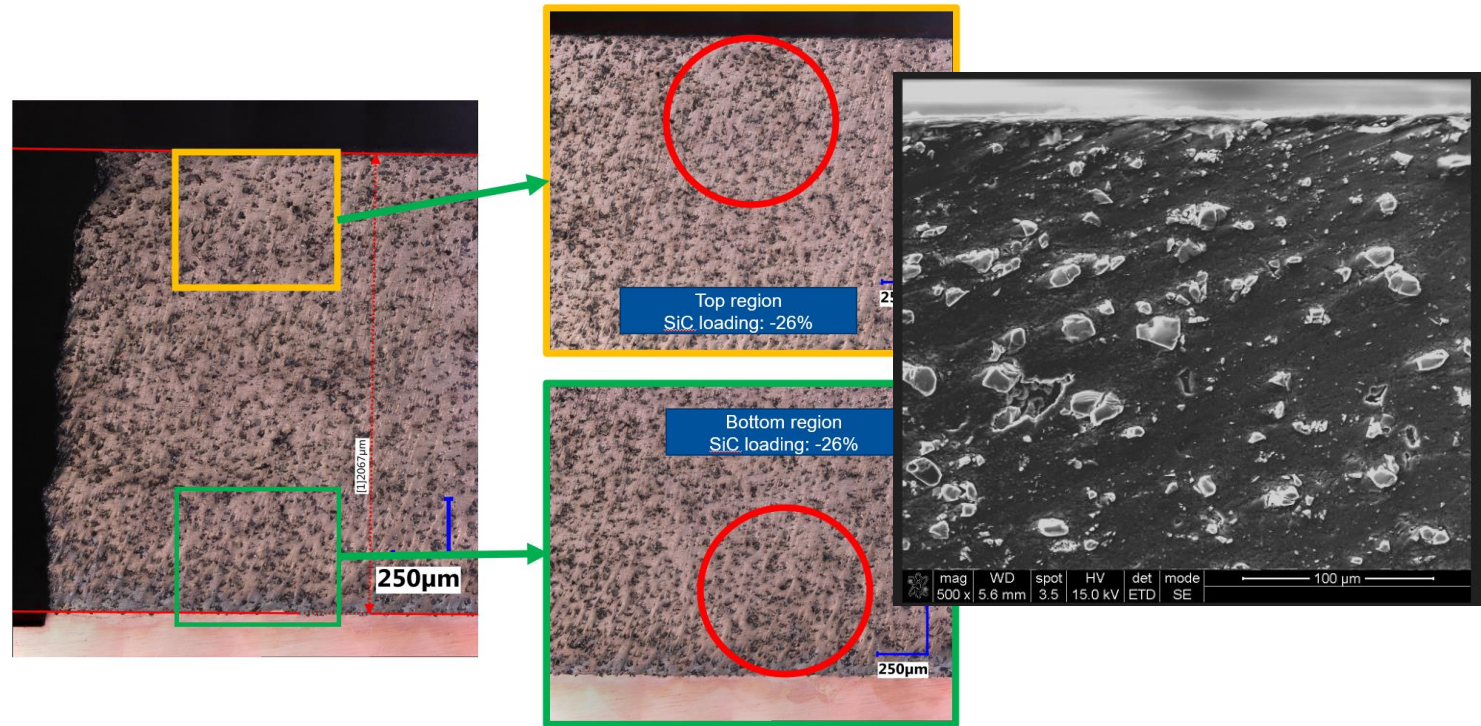
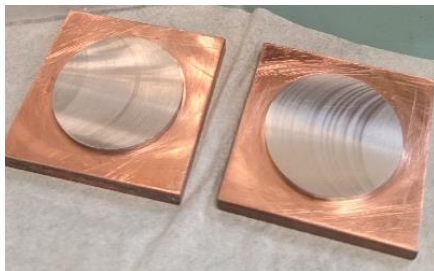
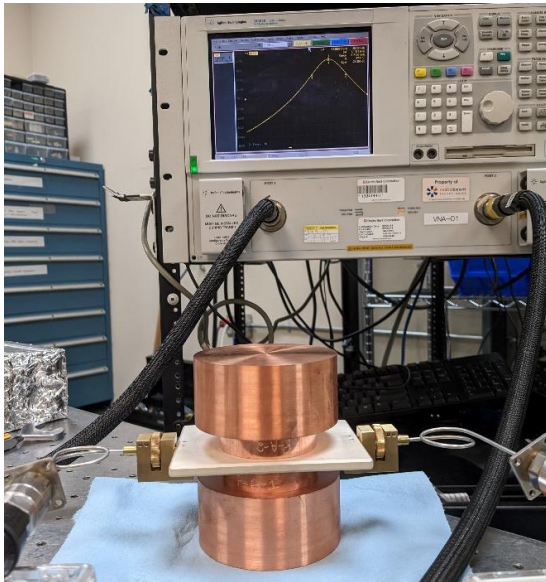
2MW S-band dry load at SLAC flame spray with Kanthal
Metallic/resistive loss = large surface area

- Issues regarding loading SiC into cold spray coating: Multiple vendors and discussions
 - Ductile matrix with brittle particles needed for adhesion: Max loading was 26% SiC
- 6 GHz dielectric cavity measurements show 'metal' behavior with $\sigma = 20\text{-}25\%$ IACS

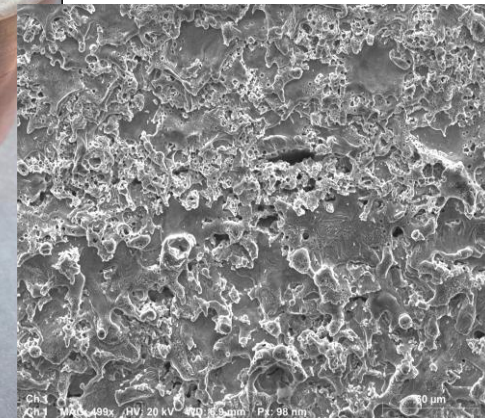


$f_0 = 3.0\text{GHz}$
 $\sigma = 29\%$ IACS

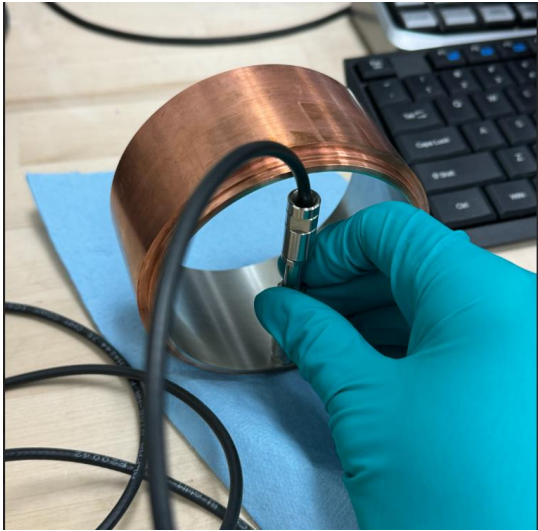
8/14/2023



- Nichrome Ni-20Cr cold spray coating:
 - Praxair– PWA 1319: good corrosion resistance, ceramic bond coat, general repair
 - $\sigma = 1.5$ %IACS
- Coating thickness hard to control & porosity of top layer is high
- Thin (50 μm) final coating: turn ID & OD



- Turned ID: 100 + 25 μm thickness



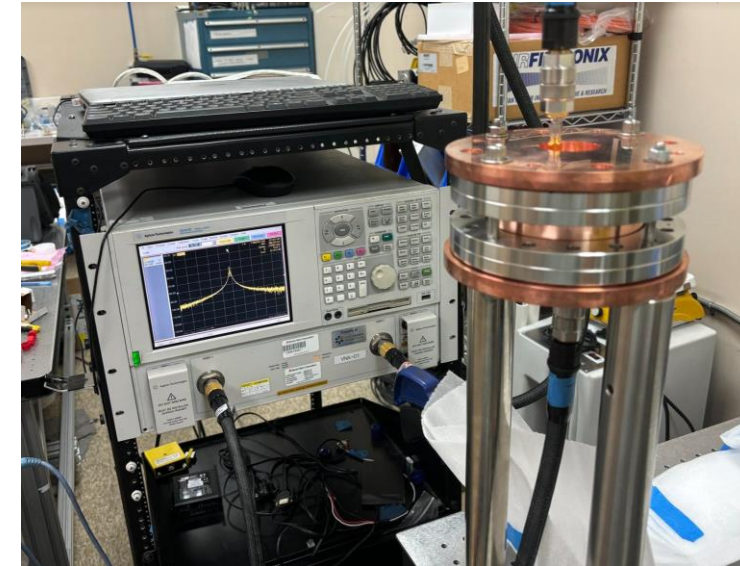
480kHz Eddy current
 $\sigma = 2.1 \pm 0.9$ %IACS
 $\delta = 12\mu\text{m}$



2.8GHz pillbox
 $\sigma = 3.1$ %IACS
 $\delta = 0.12\mu\text{m}$

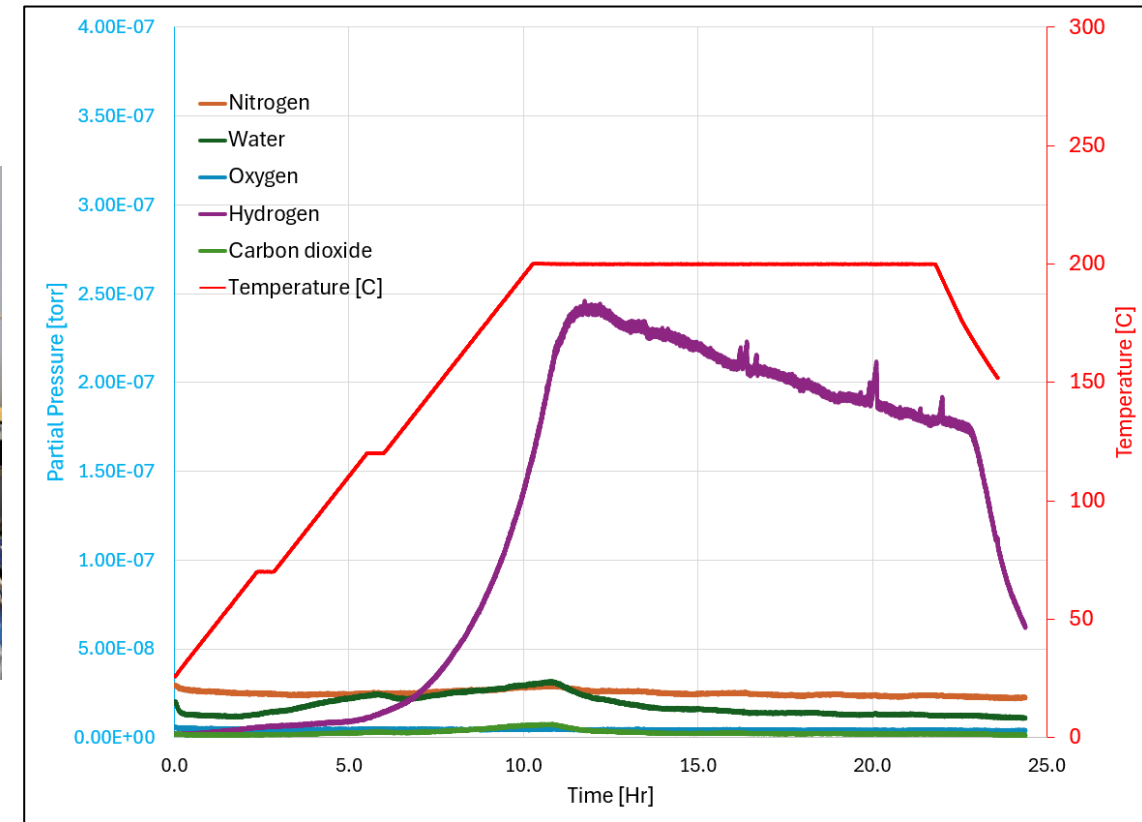
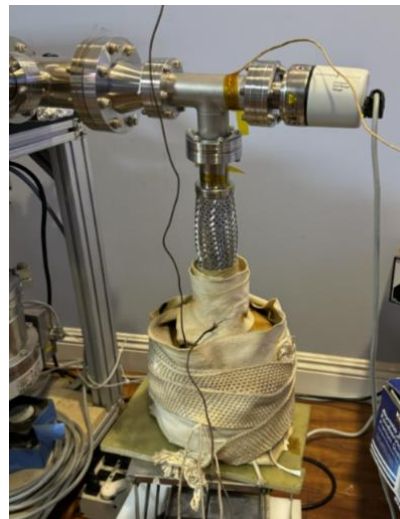
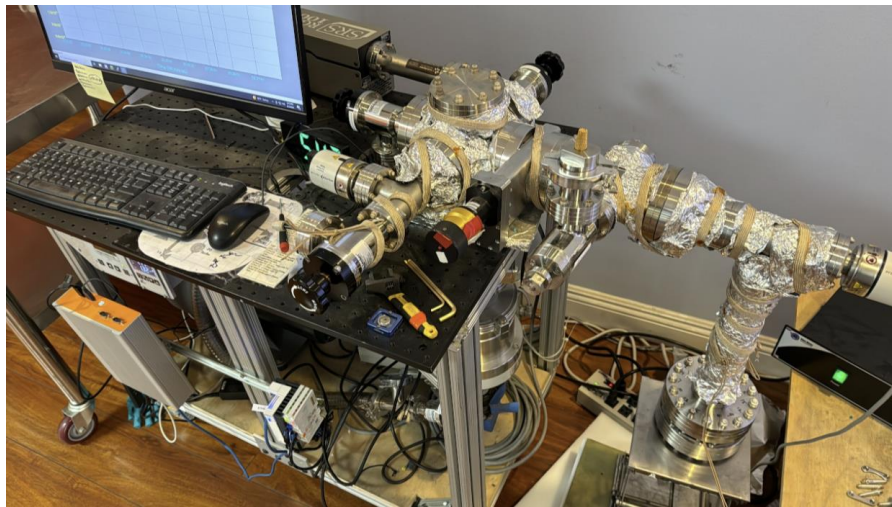


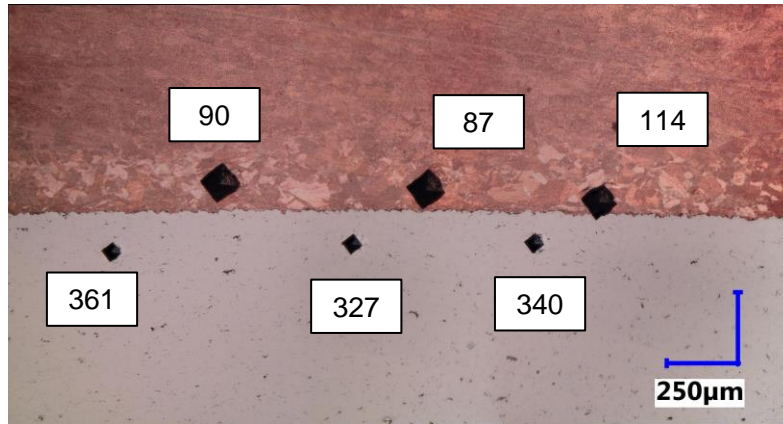
Cu-25Au vacuum
 brazing



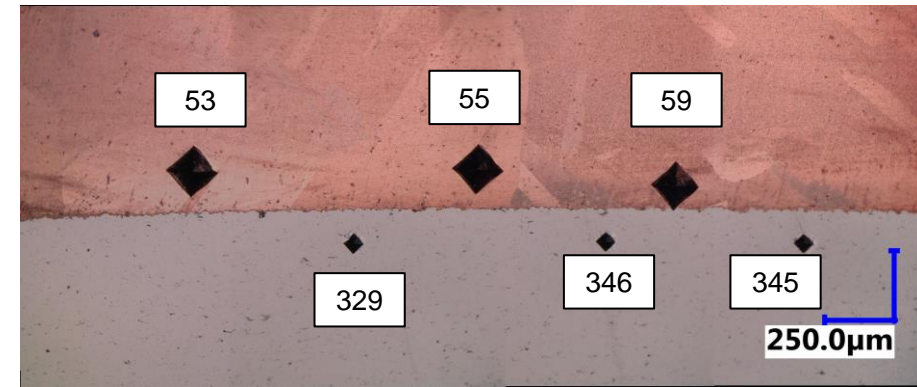
2.8GHz pillbox
 $\sigma = 4.1$ %IACS
 $\delta = 0.12\mu\text{m}$

- Braze body passed He leak check
- Base pressure: 7.9×10^{-8} Torr
- Bake-out: 200C for 12hrs
- Significant H outgassing from RGA signal

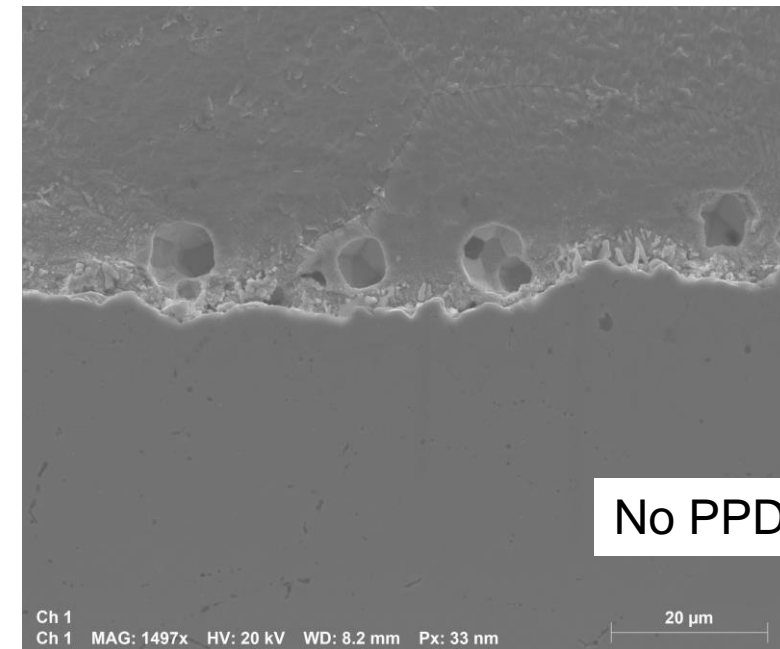
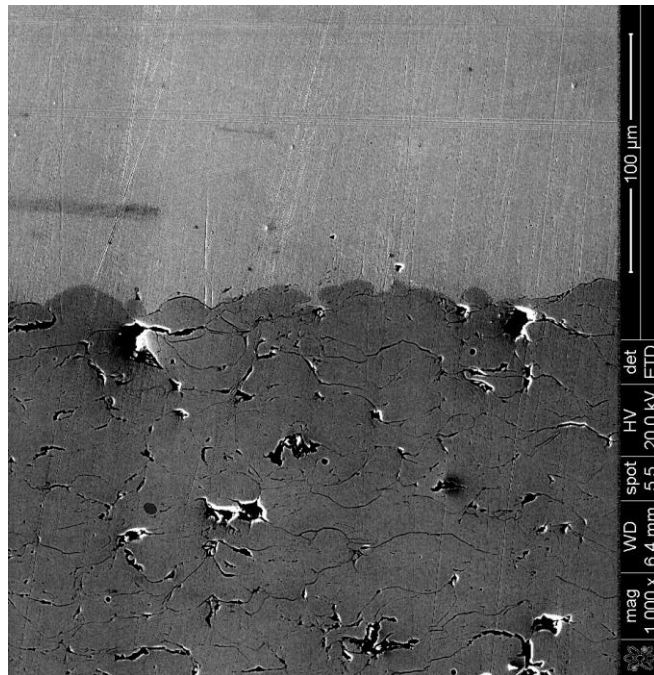




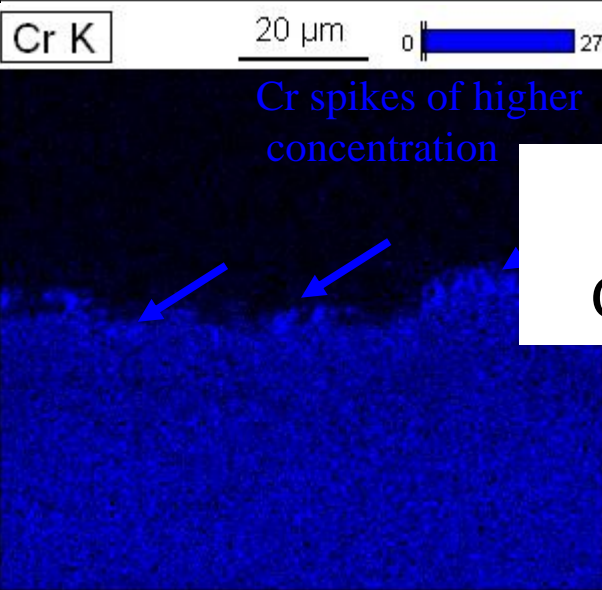
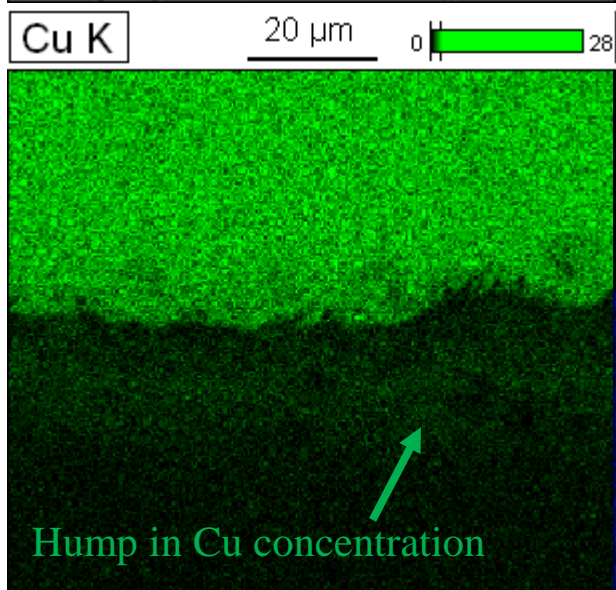
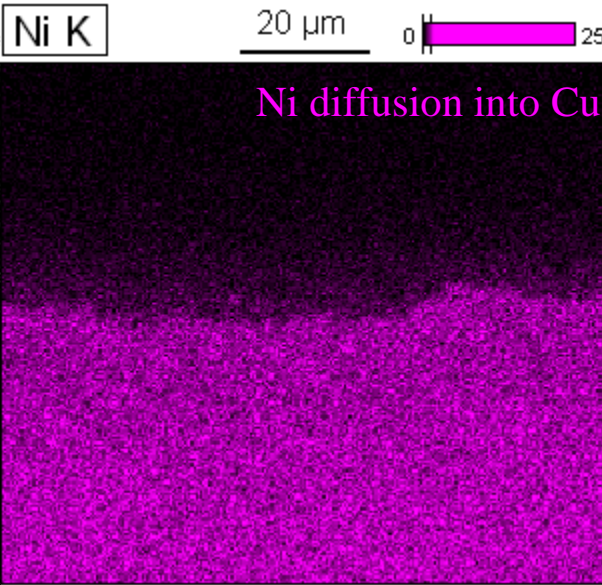
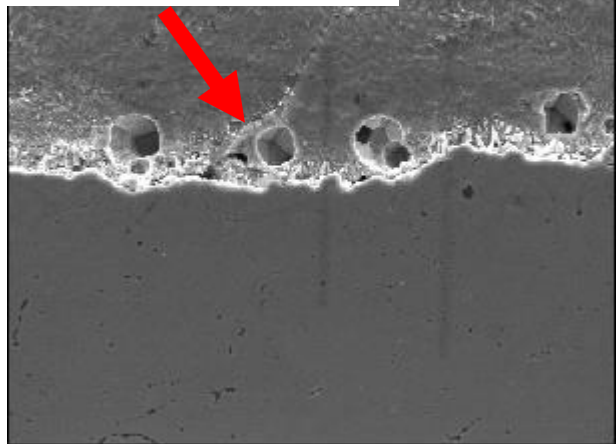
As-sprayed



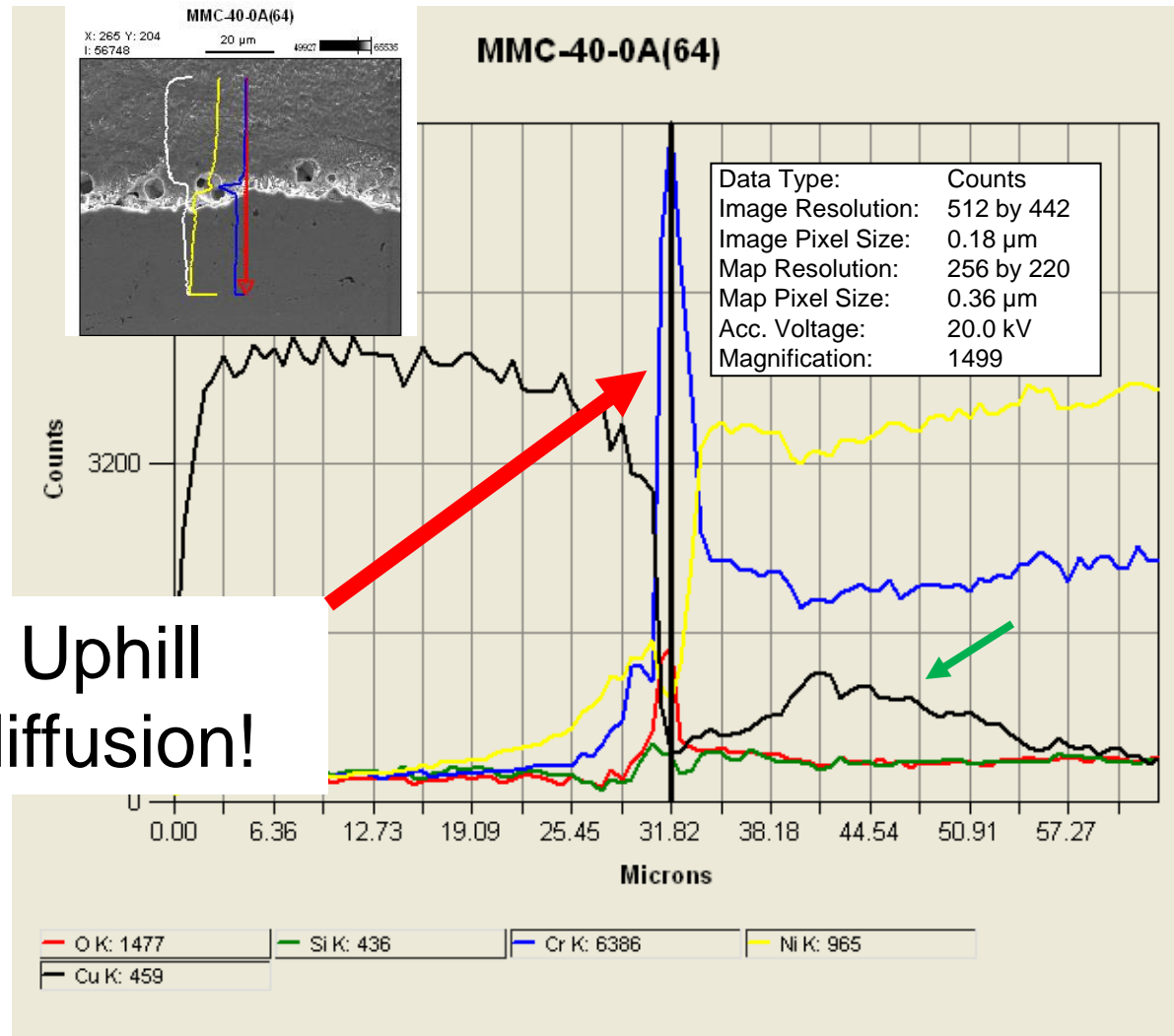
Brazed



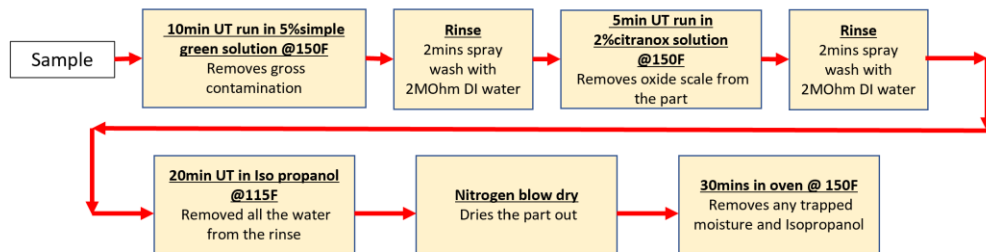
Kirkendall porosity



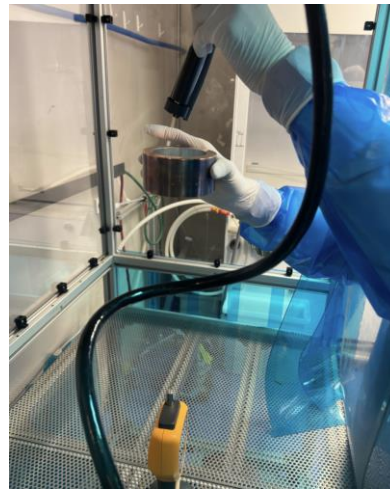
Uphill diffusion!



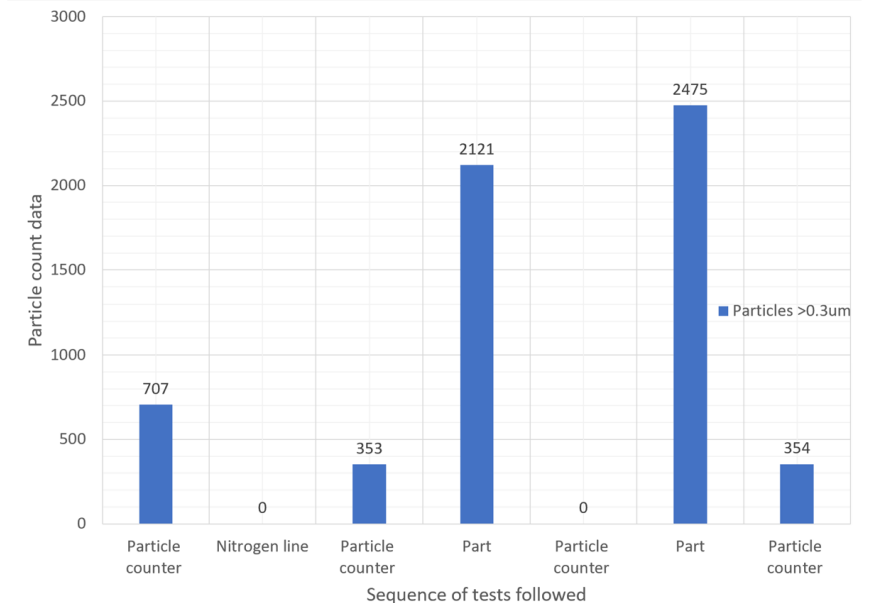
- Contaminate and particulate free BLAs critical to UHV beamline operation near SRF cavities
- Cleaning performed at Radiabeam:
 - 2M Ω -cm Type 2 DI water;
 - Custom 40kHz, 45 W/L large ultrasonic tank for cleaning large assemblies (27"x 20" x 14")
- Particulate count testing performed in ISO5 hood according standards
 - ASTM E2042/2042M *Standard Practice for Cleaning and Maintaining Controlled Areas and Clean Rooms*
 - ISO-14644-2 *Monitoring to provide evidence of cleanroom performance related to air cleanliness by particle concentration*
- 0.3 μ m and 5 μ m particle channels monitored sampled at 2.8L/min for 1 min w/ Top gun ionizer blow off gun
- Particle count high: improvements to cleaning and blow-off procedure needs



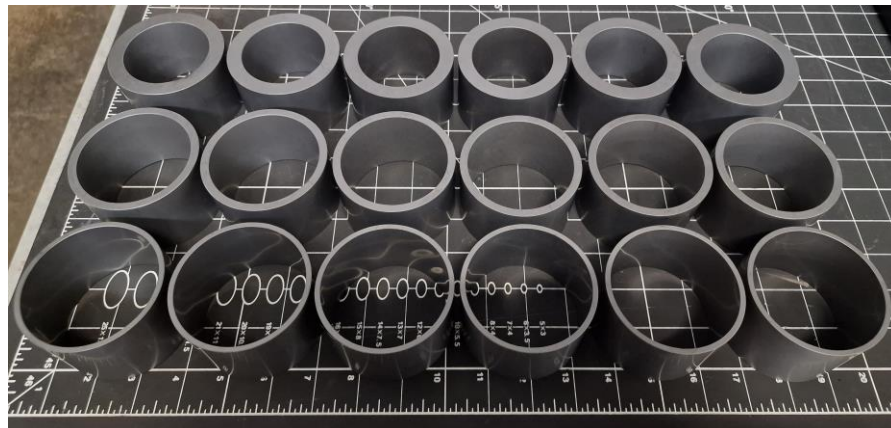
RadiaBeam BLA cleaning procedure



Particle counting in soft-wall clean hood @ RBT



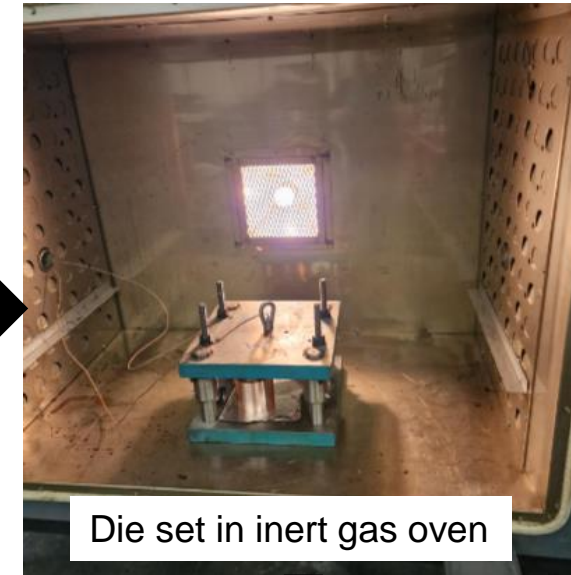
- Quality control of lossy ceramic is decades-long problem
- Coorstek SC-35: Graphite Loaded Direct Sintered Silicon Carbide
 - Oil & Gas: Dry-running bearing for extreme environments
 - Graphite: built-in lubrication
 - Side-benefit: charge dissipation
 - Similar ‘dry-running’ graphite-loaded SiC products:
 - Saint Gobain-Hexoloy SG
 - 3M EkaSiC-P



X18 SC-35 cylinders: [3,5,10]mm WT at Radiabeam



Set-up with deadweight



Die set in inert gas oven

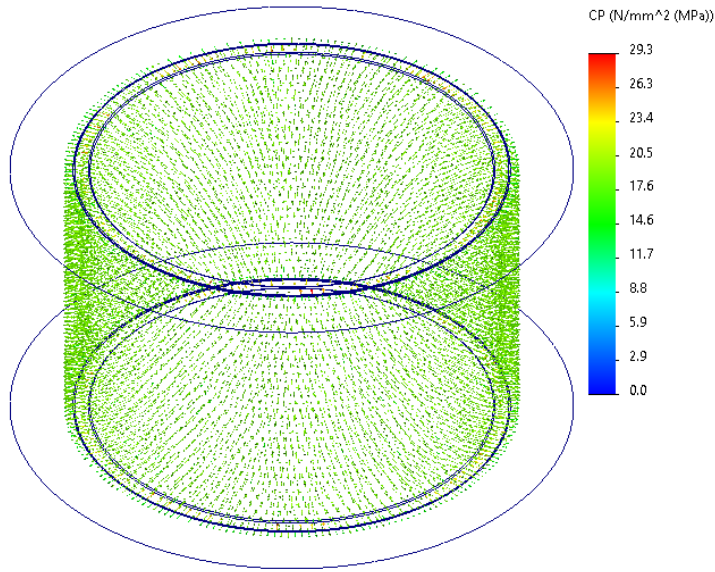


Shrink-fit SC-35 in copper



SiC fully inserted in the copper tube

Interfering Surface Radial Pressure (MPa)



Calculation Summary

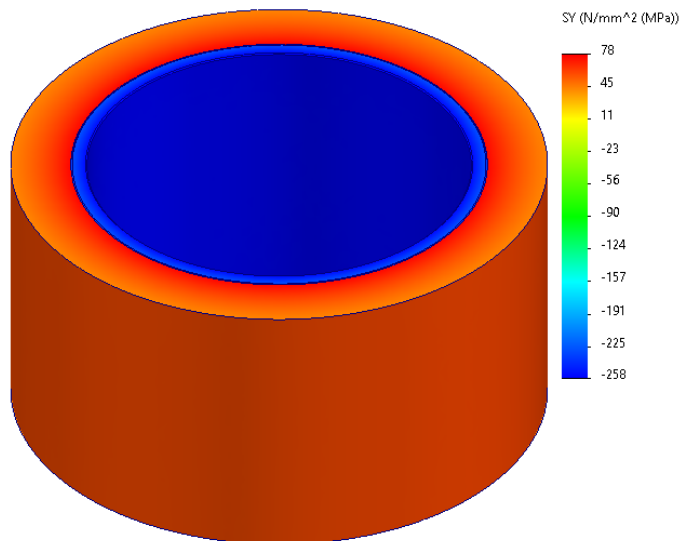
Inputs

SiC inner radius, r_i	1.398
SiC outer radius, Nominal radius R	1.516
Cu tube inner radius, R_{cu}	1.513
Cu tube outer radius, r_o	1.951

Outputs

Radial interference, δ [in]	0.0022
Heating temperature for zero clearance ΔT [°C]	141.5
Radial pressure on interfering surface, P [Mpa]	18.7
Maximum compressive stress on SiC, σ_{SiC} [Mpa]	-231.7
Maximum tensile stress on Cu tube, σ_{Cu} [Mpa]	75.8

Hoop Stresses (MPa)



Thermal expansion

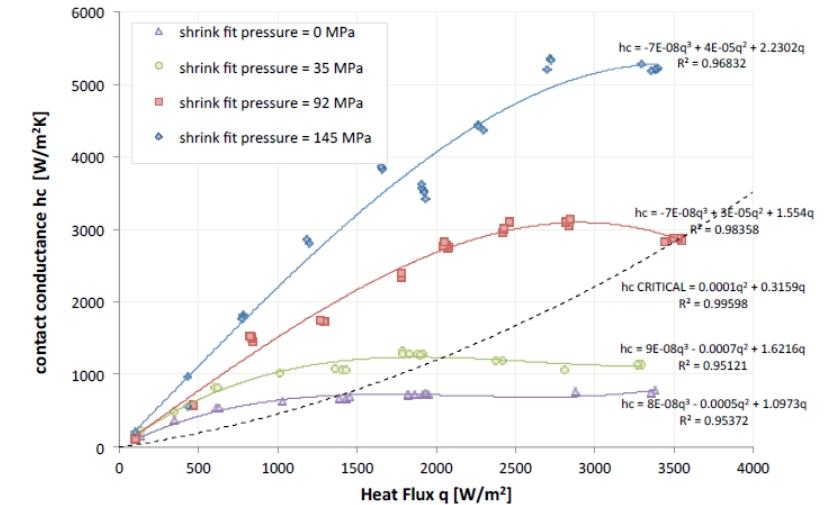
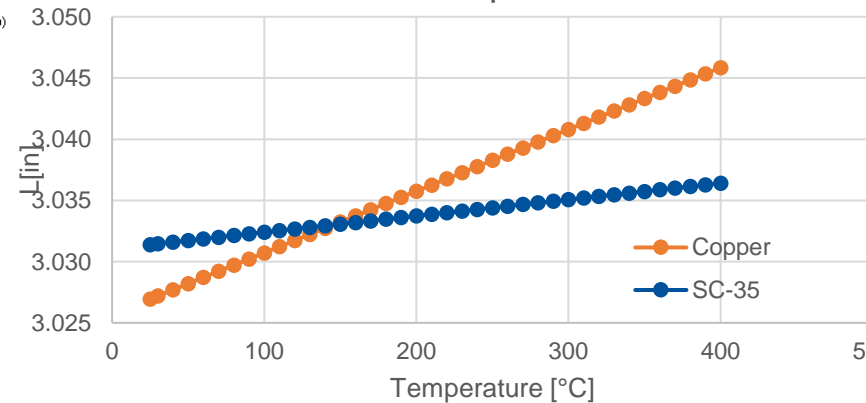
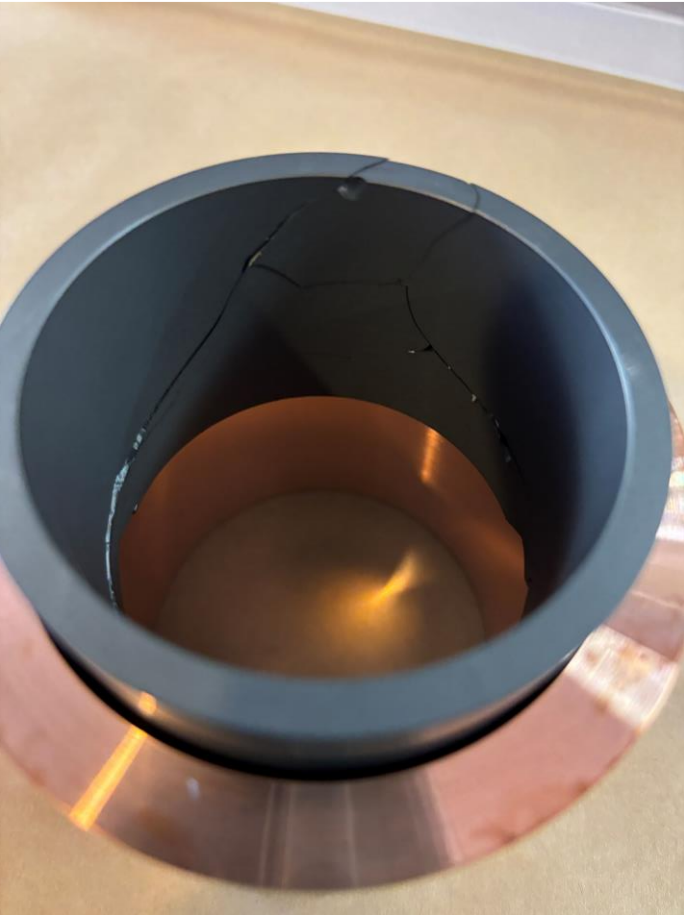
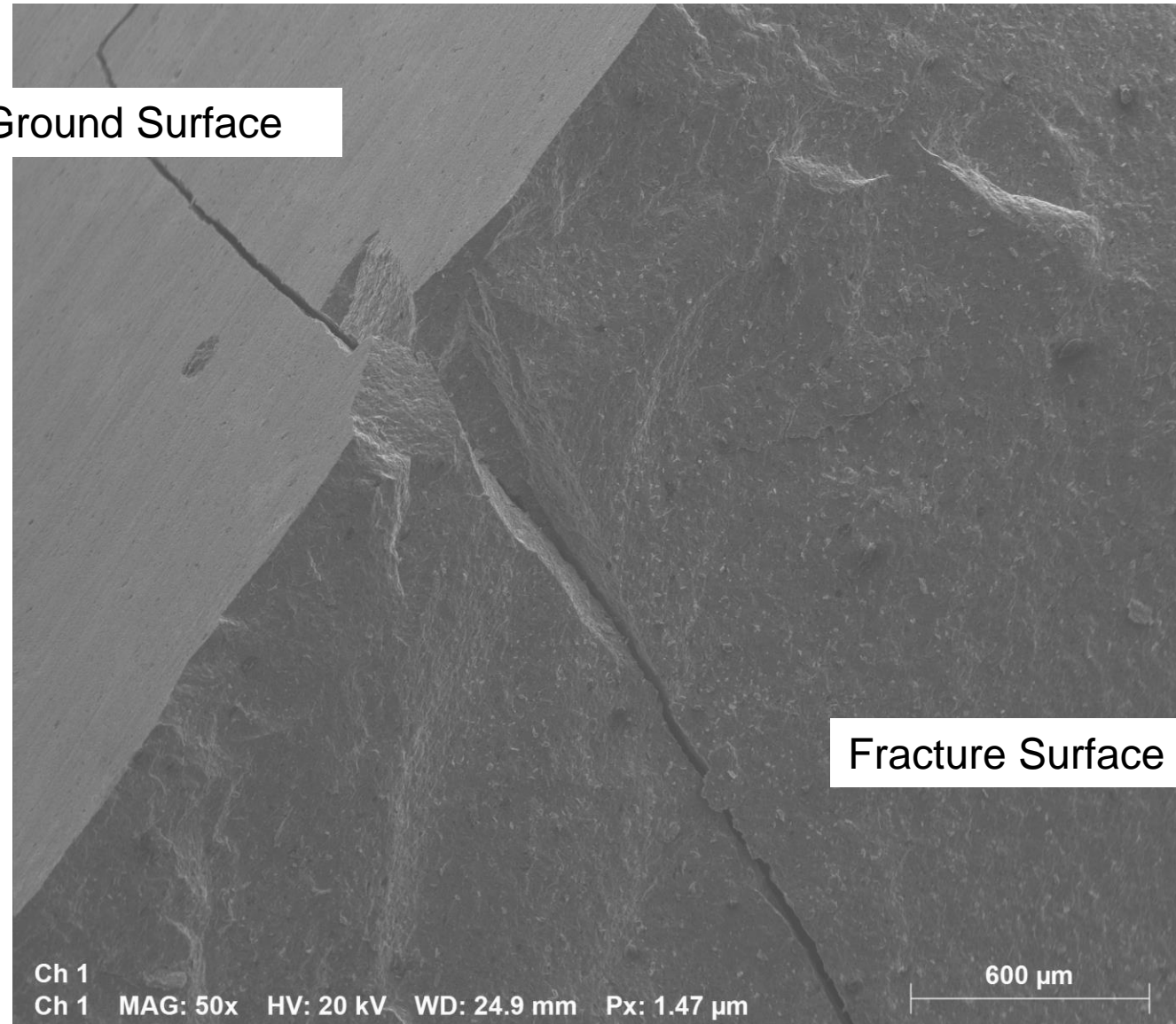


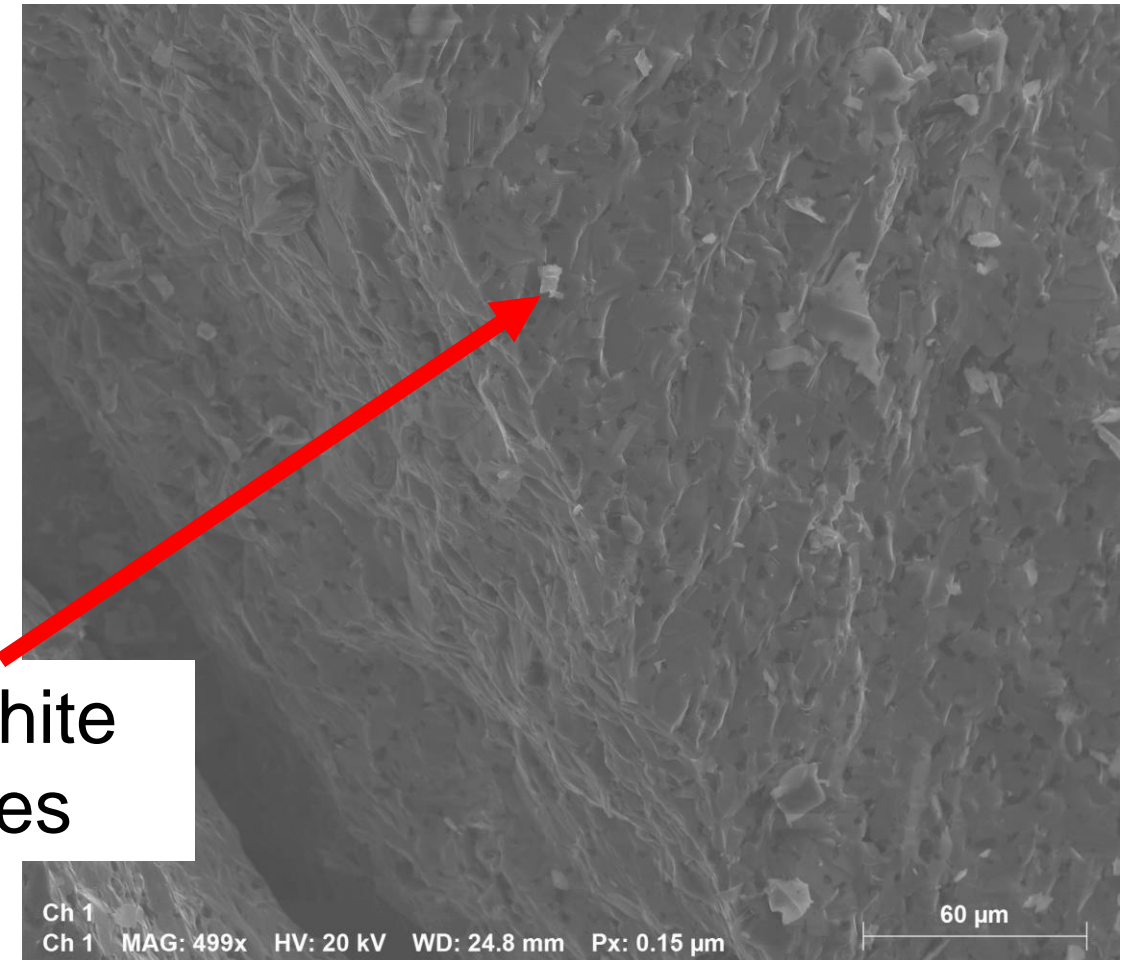
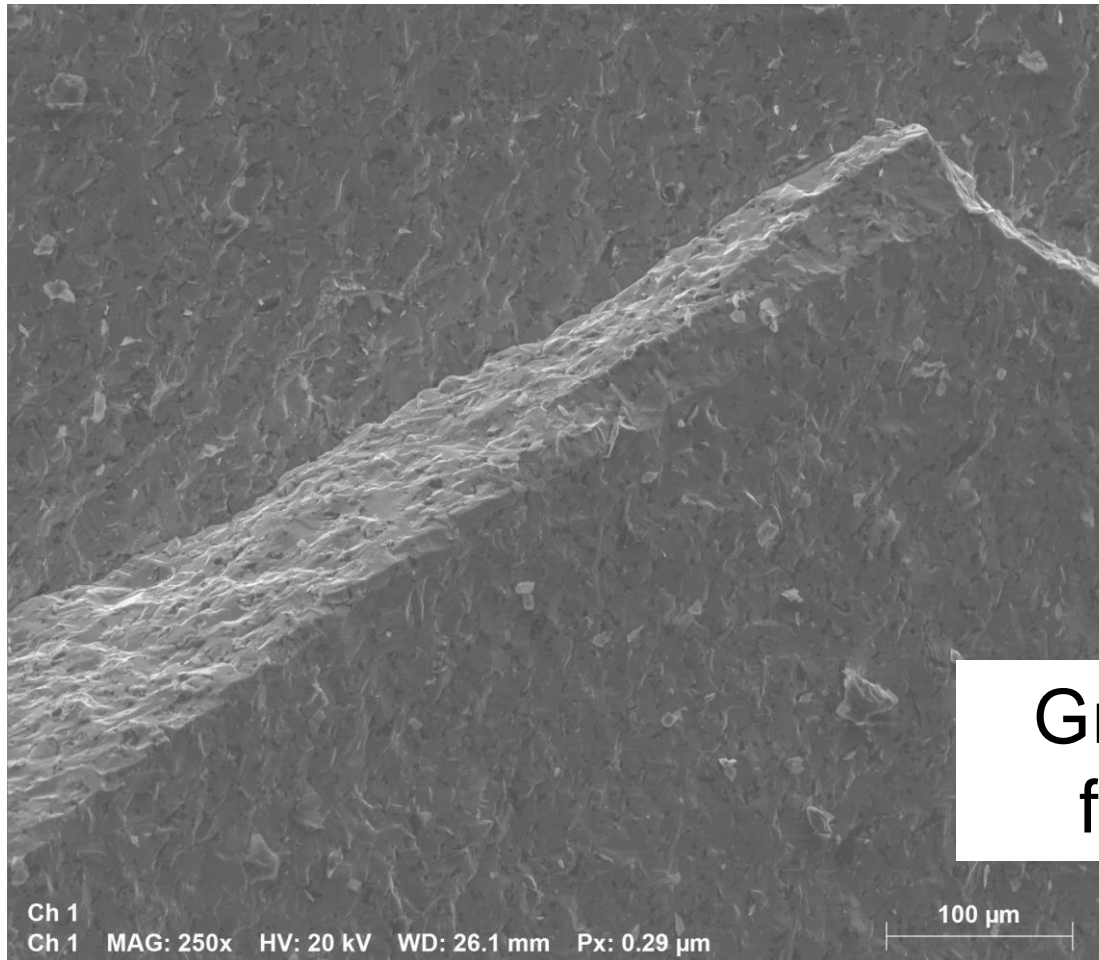
Figure 3: Chart showing measurements of how the thermal contact conductance varies with contact pressure and heat flux.



Ground Surface

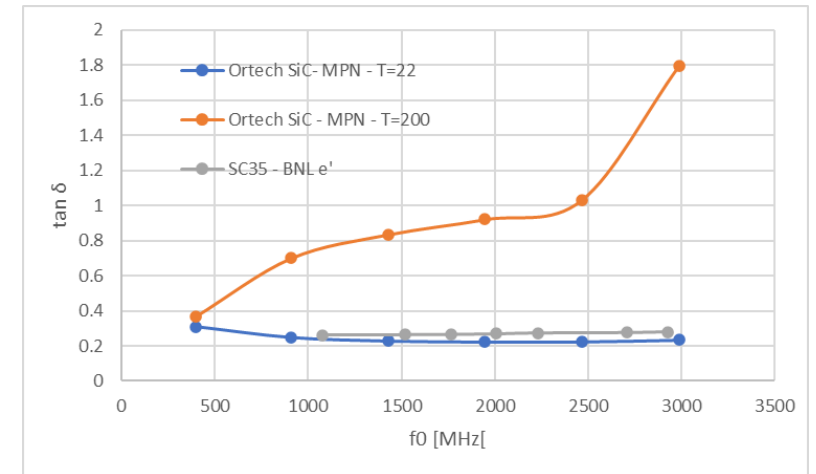
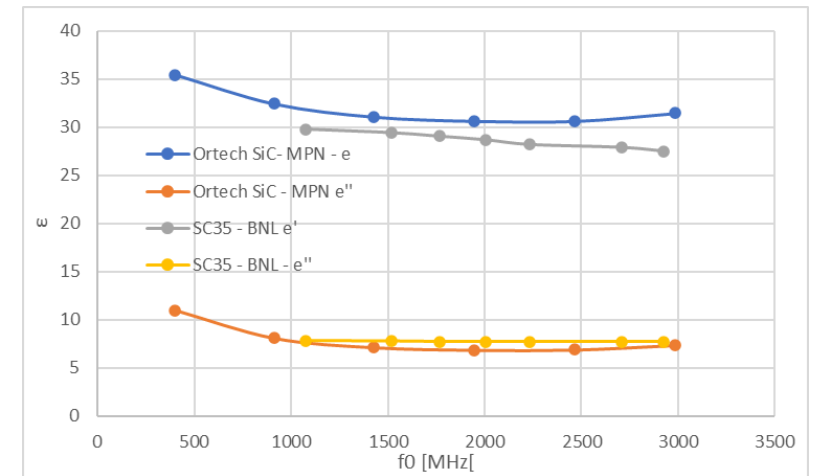
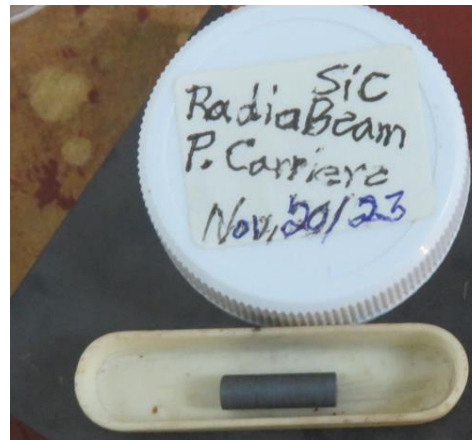
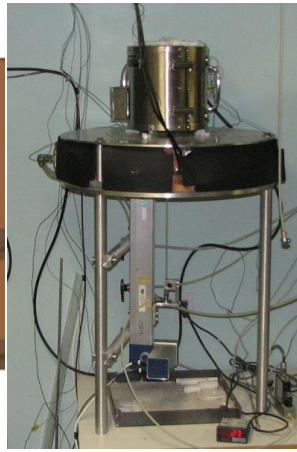
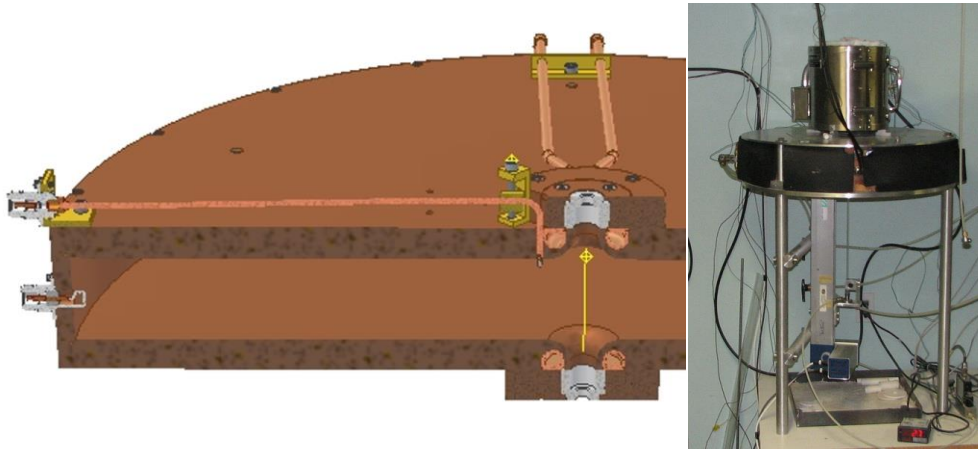


Fracture Surface

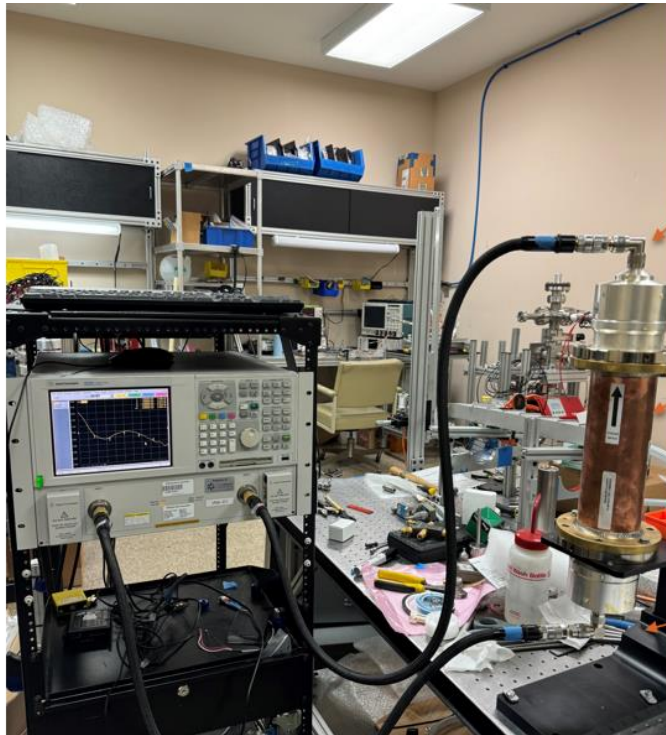
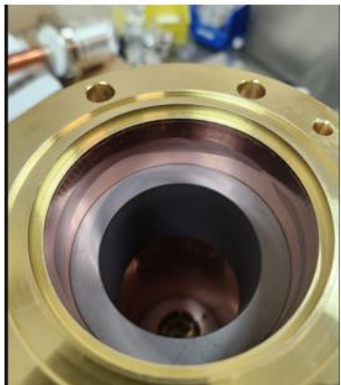
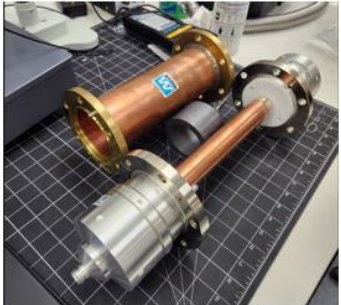


Graphite
flakes

- Microwave Properties North: dielectric characterization of lossy dielectrics
 - Prior experience with CEBAF and CESR-B absorbers
 - Fixture is capable of measuring permittivity as function of temperature, compensate for CTE effects
 - Cylindrical sample: diameter 3.70mm, length= 12.05



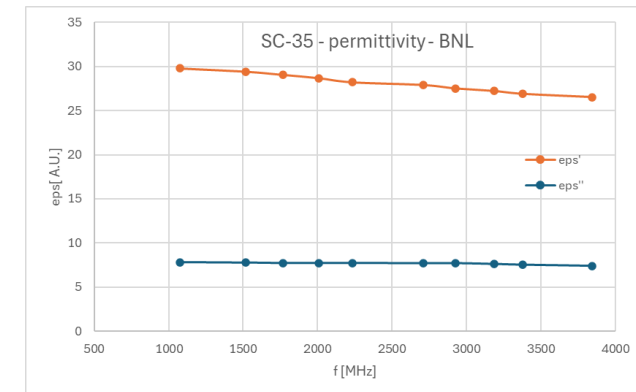
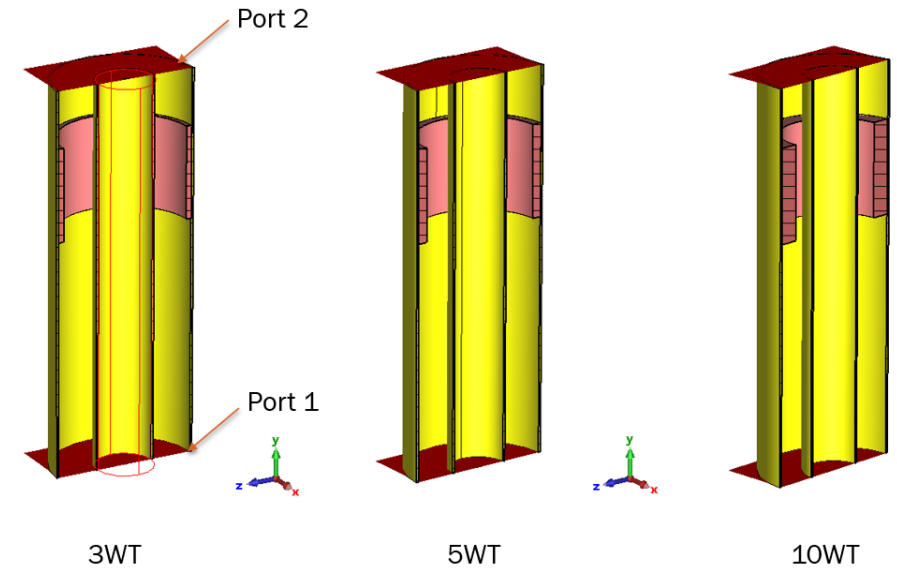
- Calibrated, low power VNA measurements performed with EIA 3 1/8" coaxial cable
- RF modelling performed in CST Studio
 - Complex permittivity data provided by BNL



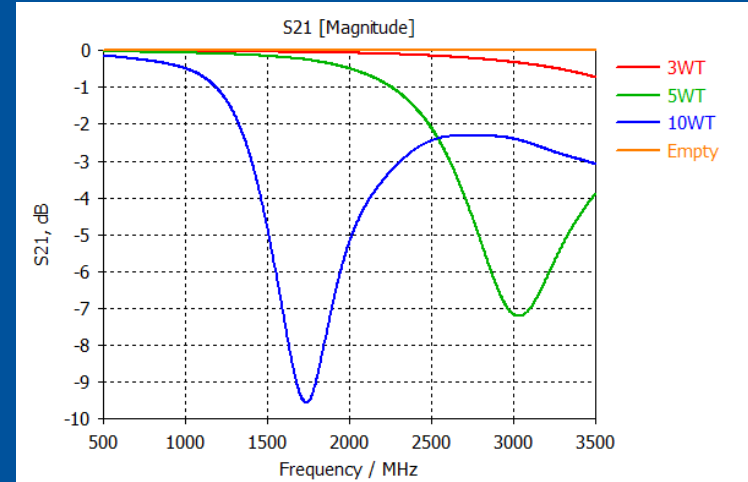
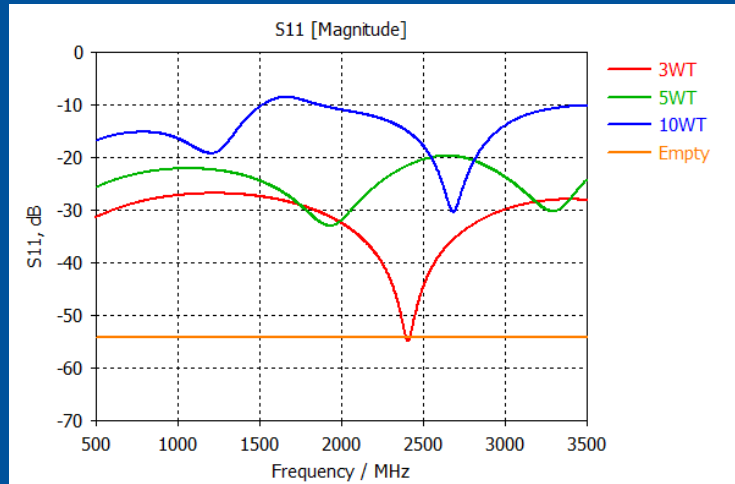
Port 2

Position of the
SiC ring

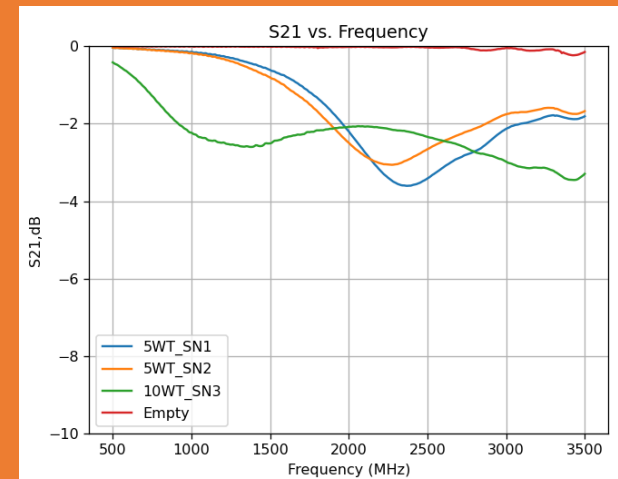
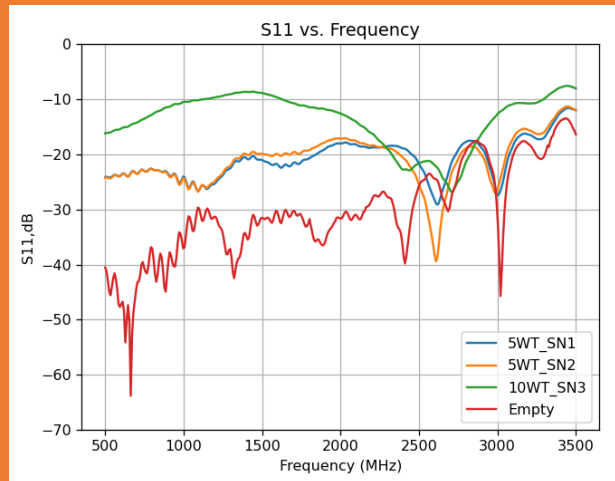
Port 1



CST Results



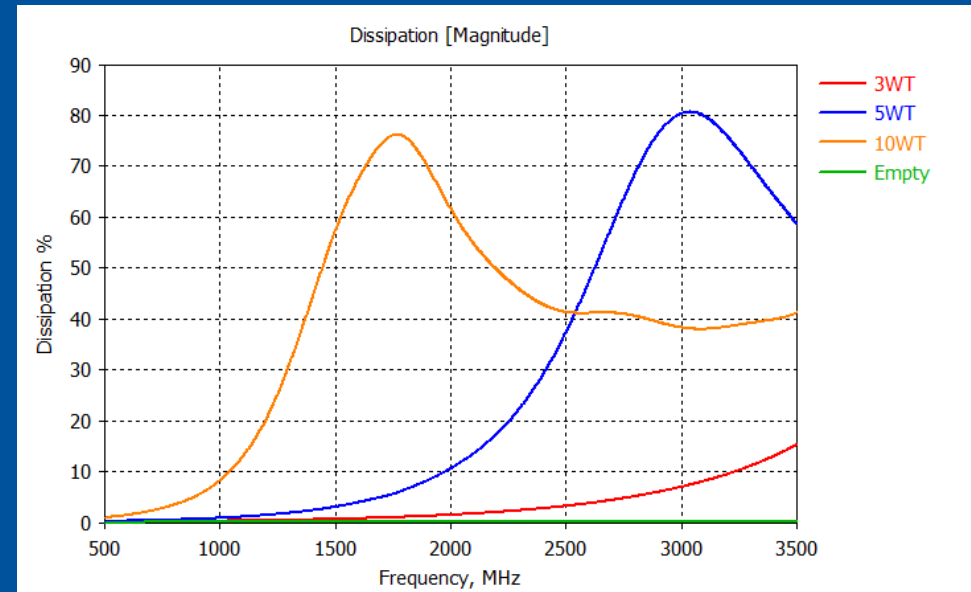
Measurement Results



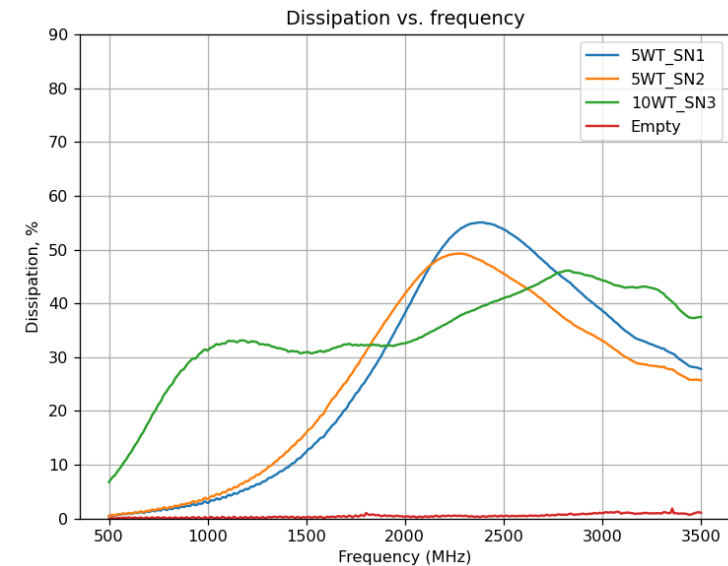
- Resonance absorption due to thickness effects of material
- Resonance frequency does not match CST
 - Differences in ϵ between material and model
- Variability in dissipation between nominally identical parts

$$\text{Dissipation \%} = (1 - S_{11}^2 - S_{21}^2) * 100$$

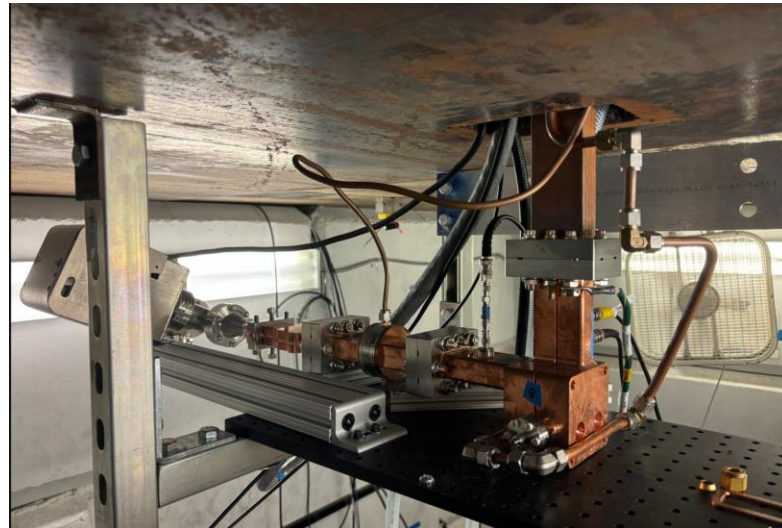
CST Results



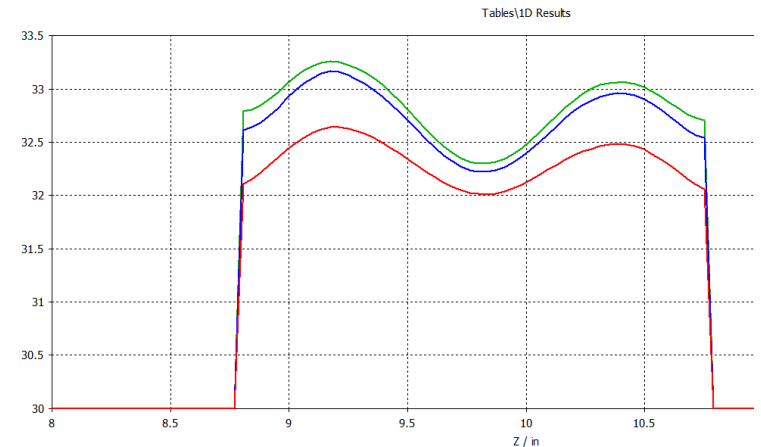
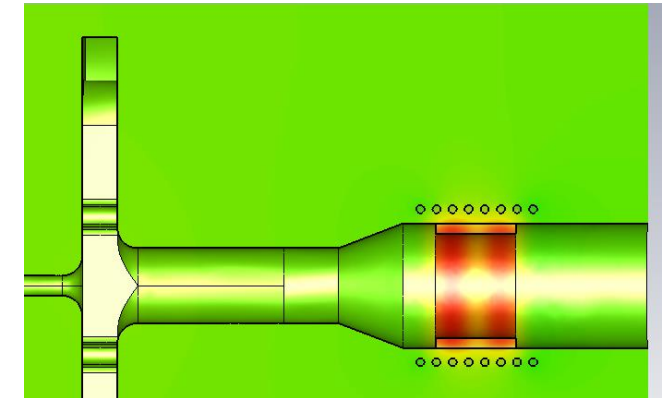
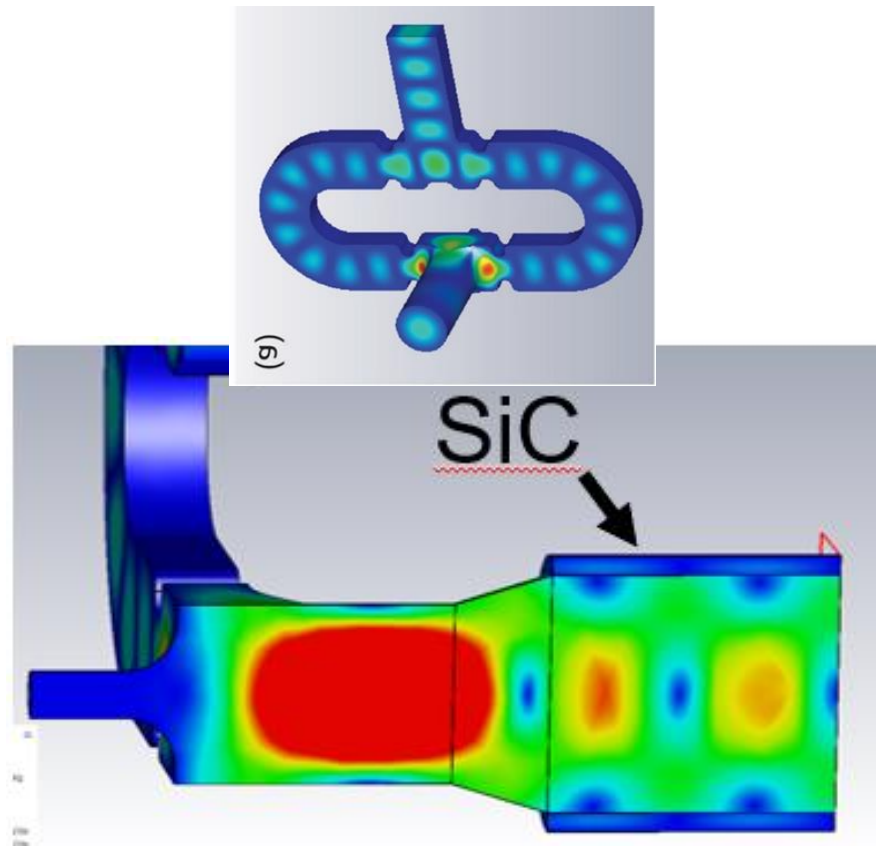
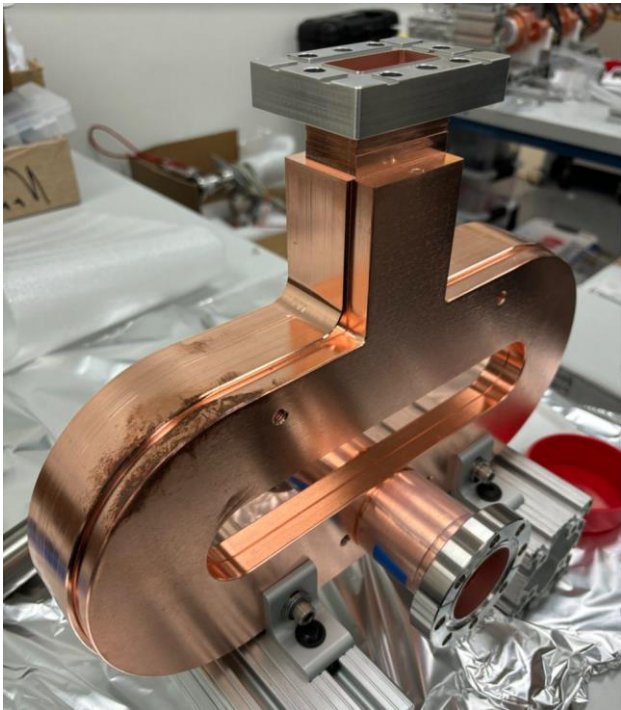
Measurement Results



- In-house high power RF testing infrastructure
- 50MW Canon klystron with Scandinova modulator, 5kW max, 5712 MHz
- Vacuum waveguides, EPICS datalogging system (radiation, vacuum, RF)
- Concrete radiation bunker rated to 21MW



- TE01 rectangular to TM01 circular mode converted
- Vacuum RF volume
- 5MW pk, (0.01% duty) 1uS pulse length 100Hz: 500W average
- Tune short but concerns about reflections to klystrons without circulator

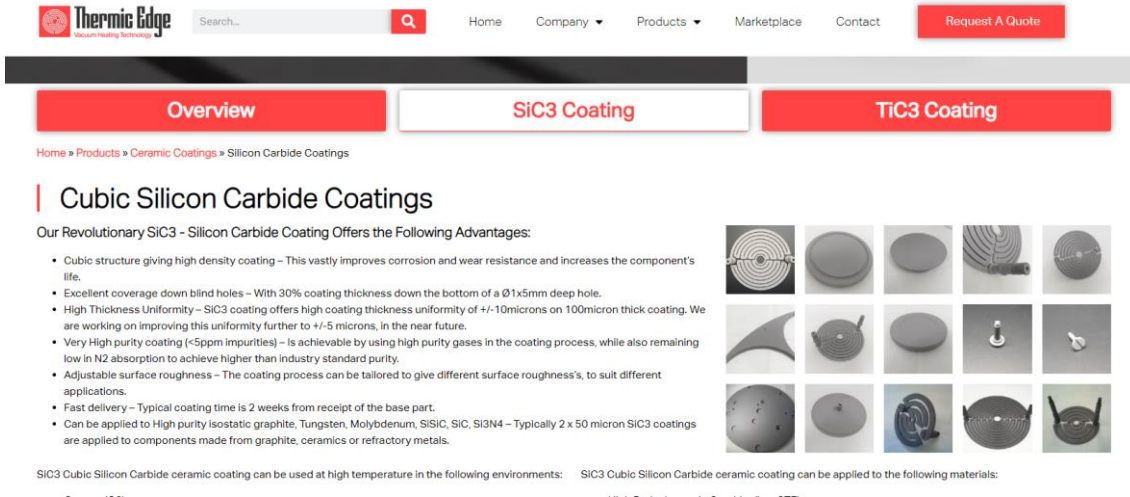


Absorbed: (450W)
 Equiv 6.1 mW/mm³ (450W)
 BNL: 5.7 mW/mm³ (20kW)
 -Reflected: 13dB (25W)
 Wall cooling: 10kW/m² K

- Testing standard: clear, unambiguous test results for dry UHV RF loads?
 - How to address variability of broadband RF data?
- Market demand signal from Lab??
 - Internal Lab development versus commercial BLAs
 - LCLS-II BLA: purchased from Europe with Sienna Tech(US) ceramic and DESY development
 - APS-U BLA: fabricated internally
 - EIC BLA: BNL LDRD for fabrication, design and testing
- Best value versus domestic production?
- SuperKEK-B upgrade, high power (37kW) BLA's were jointly developed by KEK and Toshiba Energy Systems

- Dry, UHV RF loads like BLAs have been a challenge for accelerator community
 - Demand is limited, usually ‘off-label’ application
 - Size matters: small samples \neq full size assembly
 - Variability in test results, no ‘accelerator’ focused materials qualification exists
 - Coorstek SC-35 is standard in US: Japan and Europe have demonstrated other materials SiC
- Compact BLAs: volumetric heat dissipation, lossy dielectrics with high thermal conductivity
 - Heavy ceramic loading of cold spray coatings to make into dielectric is extremely difficult
 - Outgassing from coating porosity is a challenge
 - Shrink-fit SiC BLA solution is mechanically and thermally robust
- Comprehensive testing plan for reduced diameter BLA developed
 - Cost and performance comparison between conventional ceramics and cold spray parts
 - High power tests under vacuum critical to establishing commercial product for NP community

- DOE Office of Science Nuclear Physics – Michelle Shinn
 - SBIR/STTR Award DE-SC0020562
- RadiaBeam: Kenichi Kanata, Nanda Matavalam, Camille Clement
- ANL: Michael Kelly
- JLab: Jiquan Gao & Haipeng Wang



The screenshot shows the Thermic Edge website interface. At the top, there is a navigation bar with the company logo, a search bar, and links for Home, Company, Products, Marketplace, Contact, and a 'Request A Quote' button. Below the navigation bar, there are three tabs: 'Overview', 'SIC3 Coating', and 'TIC3 Coating'. The 'SIC3 Coating' tab is selected. The main content area features a breadcrumb trail: 'Home > Products > Ceramic Coatings > Silicon Carbide Coatings'. The title is 'Cubic Silicon Carbide Coatings'. Below the title, it states 'Our Revolutionary SIC3 - Silicon Carbide Coating Offers the Following Advantages:' followed by a list of benefits:

- Cubic structure giving high density coating – This vastly improves corrosion and wear resistance and increases the component's life.
- Excellent coverage down blind holes – With 30% coating thickness down the bottom of a Ø1x5mm deep hole.
- High Thickness Uniformity – SIC3 coating offers high coating thickness uniformity of +/-10microns on 100micron thick coating. We are working on improving this uniformity further to +/-5 microns. In the near future.
- Very High purity coating (<5ppm impurities) – Is achievable by using high purity gases in the coating process, while also remaining low in N2 absorption to achieve higher than industry standard purity.
- Adjustable surface roughness – The coating process can be tailored to give different surface roughness's, to suit different applications.
- Fast delivery – Typical coating time is 2 weeks from receipt of the base part.
- Can be applied to High purity isostatic graphite, Tungsten, Molybdenum, SiSiC, SiC, Si3N4 – Typically 2 x 50 micron SiC3 coatings are applied to components made from graphite, ceramics or refractory metals.

To the right of the text is a grid of 12 images showing various coated parts, including circular discs, rings, and complex shapes, demonstrating the coating's application on different geometries.

Below the grid, there is a small text block: 'SIC3 Cubic Silicon Carbide ceramic coating can be used at high temperature in the following environments: SIC3 Cubic Silicon Carbide ceramic coating can be applied to the following materials:'

100um CVD SiC coating on tungsten

CTE: 4.2 x ppm / C

Fast delivery – Typical coating time is 2 weeks from receipt of the base part.

Can be applied to High purity isostatic graphite, Tungsten, Molybdenum, SiSiC, SiC, Si3N4

Cost: Total cost to plate x4 parts is **\$408.**